

# **Description**

Q-Tech QT800 Series Space Qualified, 100kRad(Si) Tolerant Hybrid Oscillators are Class 2 Hybrids per MIL-PRF-55310. These CMOS and Sine Wave TCXOs are hermetically sealed in a 24 pin Double Dual In-Line, 24 pin Flat-Pack .975" x 1.275", or 32 pin Flat-Pack 1" SQR, and operate over a variety of voltages and temperature ranges.

#### **Features**

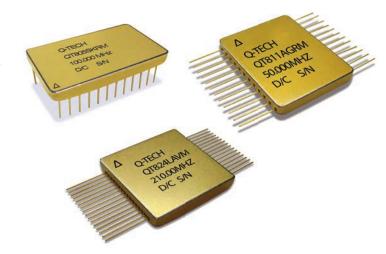
- Made in USA
- Hermetically sealed packages
- Supply voltage 3.3Vdc, 5.0Vdc, 12.0Vdc, and 15.0Vdc
- Temperature range -40°C to +85°C
- Screened and Quality Conformance Inspection to MIL-PRF-55310
- CMOS & Sine Wave outputs
- 100k(Si) Radiation tolerant
- Low phase noise and jitter
- NEW: Low Noise option for even lower phase noise on our Sine Wave output TCXOs.

### **Packaging Options**

Standard ESD packaging

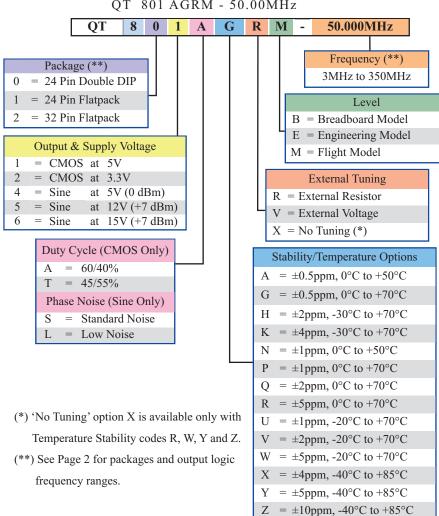
### **EAR Destination Control Statement**

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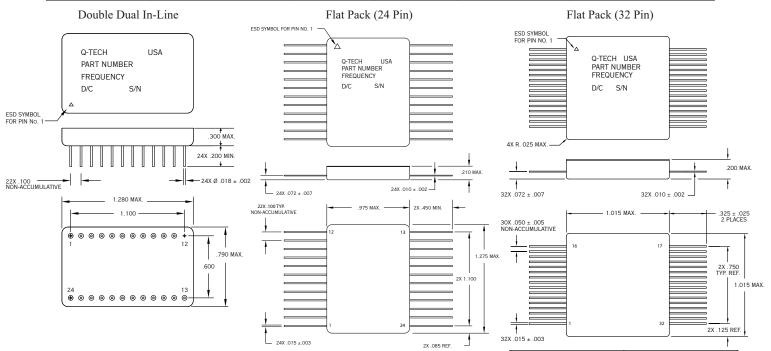
# **Ordering Information**

(Sample part number)
QT 801 AGRM - 50.00MHz





| Photo  | Package                         | Product<br>QT                             | Output<br>Logic                      | Vdd (V)                        | Frequency<br>Range  |
|--|---------------------------------|---|--------------------------------------|--------------------------------|---|
| and the state of t | Double Dual In-Line<br>(24 Pin) | QT801<br>QT802<br>QT804<br>QT805<br>QT806 | CMOS<br>CMOS<br>Sine<br>Sine<br>Sine | 5V<br>3.3V<br>5V<br>12V<br>15V | 3MHz to 90MHz<br>3MHz to 90MHz<br>10MHz to 150MHz<br>10MHz to 150MHz<br>10MHz to 150MHz |
| o concluded a conc | Flat Pack<br>(24 Pin)           | QT811<br>QT812<br>QT814<br>QT815<br>QT816 | CMOS<br>CMOS<br>Sine<br>Sine<br>Sine | 5V<br>3.3V<br>5V<br>12V<br>15V | 3MHz to 90MHz<br>3MHz to 90MHz<br>10MHz to 350MHz<br>10MHz to 350MHz<br>10MHz to 350MHz |
| o officiality  | Flat Pack<br>(32 Pin)           | QT821<br>QT822<br>QT824<br>QT825<br>QT826 | CMOS<br>CMOS<br>Sine<br>Sine<br>Sine | 5V<br>3.3V<br>5V<br>12V<br>15V | 3MHz to 90MHz<br>3MHz to 90MHz<br>10MHz to 350MHz<br>10MHz to 350MHz<br>10MHz to 350MHz |



#### Package Dimensions are in Inches

| Pin No. | Designation                       |
|---------|-----------------------------------|
| 1       | Ext. Freq. Adjust (If Applicable) |
| 2 - 11  | NC                                |
| 12      | GND/Case                          |
| 13      | RF Output                         |
| 14 - 23 | NC                                |
| 24      | Supply Voltage                    |

| Pin No. | Designation                         |  |  |
|---------|-------------------------------------|--|--|
| 1       | Ext Freq. Adjust<br>(If Applicable) |  |  |
| 2 - 11  | NC                                  |  |  |
| 12      | GND/Case                            |  |  |
| 13      | RF Output                           |  |  |
| 14 - 23 | NC                                  |  |  |
| 24      | Supply Voltage                      |  |  |

| Pin No. | Designation                       |  |  |
|---------|-----------------------------------|--|--|
| 1 - 3   | NC                                |  |  |
| 4       | Ext. Freq. Adjust (If Applicable) |  |  |
| 5       | GND/Case                          |  |  |
| 6 - 10  | NC                                |  |  |
| 11      | Supply Voltage                    |  |  |
| 12      | RF Output                         |  |  |
| 13      | Supply Voltage                    |  |  |
| 14 - 32 | NC                                |  |  |

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#### 1 **PURPOSE**

1.1 The purpose of this Detail Specification Control Drawing (SCD) is to describe the specific quality and reliability requirements for a temperature compensated crystal oscillator (TCXO).

#### 2 SCOPE

2.1 This specification establishes the minimum detail requirements for a low profile hybrid, hermetically sealed, Type 3, Class 2 (reference MIL-PRF-55310) TCXO.

#### 3 PART PROTECTION AND SAFETY

3.1 These items are susceptible to breakdown damage resulting from electrostatic discharge. Every precaution shall be taken while handling, installing, and testing the parts to prevent static charge. Care should be exercised to not apply more than rated voltage or current to any terminal/pad during testing.

#### 4 PART NUMBER

4.1 The Q-Tech Part Number shall be as specified in Ordering Information (Page 1).

# 5 APPLICABLE DOCUMENTATION & REFERENCES

- 5.1 The following documents form a part of this drawing to the extent specified or modified herein.
- 5.2 Military & Industry
- 5.2.1 MIL-PRF-55310, Oscillator, Crystal Controlled, General Specification for
- 5.2.2 MIL-PRF-38534, Microcircuit Manufacturing, General Specification for
- 5.2.3 MIL-PRF-38535, Integrated Circuits, (Microcircuits) Manufacturing, General Specification for
- 5.2.4 MIL-PRF-19500, Semiconductor Devices, General Specification for
- 5.2.5 MIL-STD-202, Test Methods for Electronic and Electrical Component Parts
- 5.2.6 MIL-STD-883, Test Methods and Procedures for Microelectronics
- 5.2.7 MIL-STD-1686, Electrostatic Discharge Control Program for Protection of Electrical and Electronic Parts, Assemblies and Equipment
- 5.3 **Q-Tech**
- 5.3.1 Form F1221, Definitions for Hybrid Product Development Levels
- 5.4 **Application of Documents**
- 5.4.1 **Issue of Documents**

Document revisions in effect on the date of the customer purchase order form a part of this drawing except as modified herein.

#### 5.4.2 **Order of Precedence**

In the event of conflict between this document and the references cited herein or other requirements, the precedence in which requirements shall govern, in descending order, is as follows:

- a) Applicable Customer Purchase Order
- b) Applicable Customer Detail SCD and/or Detail Drawing
- c) Applicable Q-Tech Corporation Detail SCD/Drawing
- d) Applicable Q-Tech Corporation General SCD
- e) Other Specifications, Standards, and Documentation Referenced Above

# 5.4.3 Customer Purchase Order Special Requirements

Additional special requirements shall be specified in the applicable customer purchase order when additional requirements or modifications are needed for compliance to special programs or product line compliance. Unique identification of the items produced may be required.

### 5.4.4 General Specification Control Drawing

Any reference to the "general specification" or "general SCD" refers to the Q-Tech Corporation General Specification Control Drawing cited in the Applicable Documentation and References section, unless otherwise specified.

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#### 6 **REQUIREMENTS**

### 6.1 **General Definition**

The TCXO is a high reliability signal generator that provides a sine-wave or CMOS output. The TCXO has been designed to operate in a spaceflight environment with an expected lifetime in excess of 15 years. Life time is defined as the sum of operational and storage environments

#### 6.2 Electrical Characteristics

The electrical characteristics shall be as specified in Table II and Table III.

## 6.3 **Absolute Maximum Rating**

The absolute maximum ratings shall be as specified in Table I.

#### 6.4 **Physical Characteristics**

#### 6.4.1 **Dimensions**

The TCXO outline dimensions and terminal connections shall be as shown on Page 2.

### 6.4.2 Weight

The TCXO shall weigh less than or equal to 25 grams.

#### 6.4.3 Materials

The TCXO package body and lead finish shall be gold in accordance with MIL-PRF-38534.

### 6.5 **Design and Construction**

The design and construction of the crystal oscillator shall be as specified herein. As a minimum, the oscillators shall meet the design and construction requirements of MIL-PRF-55310, except element evaluation shall be as specified in 6.5.

6.5.1 All piece parts shall be derived from lots that meet the element evaluation requirements of MIL-PRF-38534, Class K, with the following exceptions:

#### 6.5.1.1 Active elements

a) Visual Inspection of Silicon on Sapphire Microcircuits

Semicircular crack(s) or multiple adjacent cracks, not in the active area, starting and terminating at the edge of the die are acceptable. Attached (chip in place) sapphire is nonconductive material and shall not be considered as foreign material and will be considered as nonconductive material for all inspection criteria.

### b) Subgroup 4, Scanning Electron Microscope (SEM) Inspection

The manufacturer may allow the die distributor, at his option, to select two (2) dice from a waffle pack (containing a maximum quantity of 100 die), visually inspect for the worst case metallization of the 2 dice, and take SEM photographs of the worst case.

#### c) Subgroup 5 Radiation Tests

Subgroup 5 radiation tests are not required unless otherwise specified in the detail purchase order.

#### 6.5.2 **Processes**

Processes used for manufacturing the TCXO are selected on the basis of their ability to meet the quality requirements for space High Reliability manufacturing. Travelers or Process Cards are used in the manufacturing and testing of all of the TCXO Series, and might be available for customer review. Copies of these Travelers can be provided with the TCXOs at time of shipment if so specified on the purchase order.

# 6.5.3 **Interchangeability**

Each TCXO shall be interchangeable without using a special selection process.

### 6.5.4 **Product Marking**

Each unit shall be permanently marked with the manufacturer's name or symbol, part number, lot date code number, and serial number. The unit shall be marked with the outline of an equilateral triangle near pin 1 to show that it contains devices which are sensitive to electrostatic discharge.

### 6.6 **Parts Program**

Devices delivered to this specification represent the standardized Parts, Materials and Processes (PMP) Program developed, implemented and certified for advanced applications and extended environments.



# 6.6.1 Quartz Crystal Resonator

The crystal resonator used shall be constructed using a 4-point mount premium synthetic swept Quartz and procured to Q-TECH SCD. (For the Breadboard and Engineering models, non-swept quartz may be used. See Q-Tech Form F1221, Definitions for Hybrid Product Development Levels).

### 6.6.2 Sine-Wave Active Devices

Radiation testing is not performed at the oscillator level, but these TCXOs have been acceptable for use in environments up to 100k rads by analysis of the components used. ONLY Bipolar semiconductors are employed in the design. This device is specified to be radiation tolerant to 100 kRad(Si) total ionizing dose (TID).

#### 6.6.3 **CMOS Active Devices**

Radiation testing is not performed at the oscillator level, but these TCXOs have been acceptable for use in environments up to 100k Rads by analysis of the components used. This device is specified to be radiation tolerant to 100 kRad(Si) total ionizing dose (TID). The microcircuit in this part shall use CMOS technology and shall be from a wafer proven to be radiation tolerant to 100kRad(Si) total ionizing dose.

### 6.6.3.1 CMOS Microcircuit Usage

For output frequencies below 14MHz, the output microcircuit shall be 54AC74, see DSCC SMD 5962-88520. For frequencies greater than or equal to 14MHz, the CMOS microcircuit shall be 54AC00, see DSCC SMD 5962-87549. These microcircuits are specified to be Single Event Latchup Free for LET up to 93 MeV-cm²/mg. For QT802, QT812, and QT822 devices above 70MHz, the manufacturer shall be National Semiconductor Corporation, otherwise the manufacturer shall be ST Microelectronics Corporation.

#### 6.6.4 **Prohibited Materials**

Materials containing more than 97% tin and materials containing measurable amounts (by common nondestructive test methods) of selenium, cadmium, or mercury shall not be used as plating, coating or base materials in the construction of parts or components. Zinc is only acceptable as an alloying element and alloys containing zinc must be covered by suitable protective plating (e.g. nickel plating). Inert oxides of the above materials are allowed.

# 6.7 **Traceability Requirements**

Material, element and process traceability requirements shall be as specified by MIL-PRF-38534 for Class K hybrids.

#### 6.8 **Data**

#### 6.8.1 **Design Documentation**

When required by the purchase order, design, topography, process and flow charts for all assembly/inspection and test operation for devices to be supplied under this specification on the initial procurement shall be established and shall be available in-plant for review by the procuring activity upon request. This design documentation shall be sufficient to depict the physical and electrical construction of the devices supplied under the specification and shall be traceable to the specific parts, drawings or part type numbers to which it applies, and to the production lot(s) and inspection lot codes under which devices are manufactured and tested so that revisions can be identified.

# 6.8.2 **Technical Data Package**

When required by the purchase order, the following design documentation and information is deliverable 30 days prior to the start of production. The Technical Data Package shall consist of the following:

- a) Assembly drawing(s).
- b) All electrical schematics and drawings not considered proprietary.
- c) The assembly and screening travelers to be used on-line to manufacture the devices supplied to this specification.

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- d) Parts and materials list.
- e) Element evaluation data confirming compliance with MIL-PRF-38534, Class K, and Prohibited Materials paragraph 3.4.3

### 6.9 **Test Report**

- 6.9.1 A test report is supplied with each shipment of oscillators and includes the following information, as a minimum:
  - a) A Certificate of Conformance to all specifications and purchase order requirements. As a minimum, the Certificate of Conformance shall include the following information:
    - 1) Purchase order number.
    - 2) Applicable part number.
    - 3) Manufacturers lot number.
    - 4) Lot date code.
  - b) Parts and materials traceability information.
  - c) Certificate of crystal sweeping.
  - d) Manufacturing lot traveler.
  - e) Screening attributes and variables data as applicable.
  - f) Quality conformance inspection attributes and variables data as applicable.
  - g) Radiographic inspection negatives.

# 6.10 **Non-Flight Oscillators**

Unless otherwise specified in data sheet, the general requirements for non-flight hardware (Breadboard and Engineering models) shall be defined in F1221, Definitions for Hybrid Product Development Levels.

# 6.11 **Screening**

Screening tests shall be in accordance with Table IV.

### 6.12 **Quality Conformance Inspection (QCI)**

Quality conformance shall be as specified herein. All records shall be traceable to the lot number and unit serial number. Samples used for Group A that pass all tests may be delivered on contract.

#### 6.12.1 Oscillator Group A Inspection

Group A testing shall be in accordance with Table V. Group A inspection shall be performed on units that have passed the screening tests. All electrical performance tests of this specification shall be performed during Group A with the exception of any tests performed as part of the final electrical testing during 100 percent screening.

# 6.12.2 Oscillator Group B Inspection

Group B inspection shall be in accordance with Table VI.

# 6.12.3 **Oscillator Group C Inspection**

Group C inspection shall be in accordance with Table VII.

# 6.12 <u>Destructive Physical Analysis (DPA)</u>

A DPA may be performed on each lot of devices in accordance with MIL-STD-883, Method 5009. The DPA shall be performed by the customer.

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# TABLE I - MAXIMUM RATINGS

| PARAMETER                          | SYMBOL           | MINIMUM | MAXIMUM | UNITS |
|------------------------------------|------------------|---------|---------|-------|
| Supply Voltage (QT8X1, 8X2, & 8X4) | Vs               | 0       | 6       | V     |
| Supply Voltage (QT8X5 or QT8X6)    | Vs               | 0       | 16.5    | V     |
| Operating Temperature Range        | Тс               | -55     | +125    | °C    |
| Storage Temperature                | Tstg             | -65     | +125    | °C    |
| Lead Solder Temperature/Time       |                  |         | +250/10 | °C/s  |
| Package Thermal Resistance         | $\theta_{ m JC}$ |         | 50      | °C/W  |

TABLE II - ELECTRICAL PERFORMANCE CHARACTERISTICS (CMOS)

| ELECTRICAL                      | SYMBOL TEST CONDITIONS   |   | LIMITS        |                |                                     |        |
|---------------------------------|--------------------------|---|---------------|----------------|-------------------------------------|--------|
| PARAMETERS                      | STWIBUL                  | TEST CONDITIONS   | MIN.          | TYP.           | MAX.                                | UNIT   |
| Frequency, Nominal              | fo                       |   | 3             |                | 90                                  | MHz    |
| Supply Voltage, Nominal         | Vs                       |   | 3.135<br>4.75 | 3.3<br>5       | 3.465<br>5.25                       | V      |
| Input Current                   | Is                       | Nominal Vs, No Load   | -             | -              | 50                                  | mA     |
| Frequency/Temperature Stability | Δf/fc (Ta)               |   | See Te        | mp. Code       | s on Pg. 1                          |        |
| Frequency Adjustment Range      | Δf/fo                    |   | ±3            | -              | -                                   | ppm    |
| Frequency/Vs                    | Δf/fc (Vs)               | ±5 % Vs @ +25°C   | -             | -              | ±1.2                                | ppm    |
| Load                            |                          |   | -             | 15             | -                                   | pF     |
| Output Voltage, High            | VOH                      |   | Vcc x 0.9     | -              | -                                   | V      |
| Output Voltage, Low             | VOL                      |   | -             | -              | Vcc x 0.1                           | V      |
| Output Waveform                 |                          |   | SQUARE        |                |                                     |        |
| Output Rise Time                | Tr                       | 10% to 90% of Vs  | -             | -              | 5                                   | ns     |
| Output Fall Time                | Tf                       | 90% to 10% of Vs  | -             | -              | 5                                   | ns     |
| Duty Cycle                      | DC                       | Code A<br>Code T  | ,             | 60/40<br>45/55 |                                     | %      |
| Frequency/Load Stability        | Δf/fc (Load)             | Load ±5%,<br>Vs Nom. @ +25°C  | -             | -              | ±0.3                                | ppm    |
| Aging, Max. (Note 1)            | Δf/fo                    | Over 18 Years   | -             | -              | ±4                                  | ppm    |
| Frequency Stability vs. Vacuum  | Δf/fo                    | Guaranteed by<br>Design, Not Tested   | -             | -              | ±0.2                                | ppm    |
| Short Term Stability            | $\Delta f/dc (\Delta t)$ | $\Delta t = 1s$ (Allan Deviation)   | -             | -              | 0.001                               | ppm    |
| Phase Noise @ Frequency Offset  | £ (\Delta f)             | $\Delta f = 10 \text{Hz}$ $\Delta f = 100 \text{Hz}$ $\Delta f = 1 \text{kHz}$ $\Delta f = 10 \text{kHz}$ $\Delta f = 100 \text{kHz}$ | -             | -              | -70<br>-100<br>-130<br>-140<br>-140 | dBc/Hz |

**Note:** 1. Consult with factory for better Aging performance.

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# TABLE III - ELECTRICAL PERFORMANCE CHARACTERISTICS (SINE-WAVE)

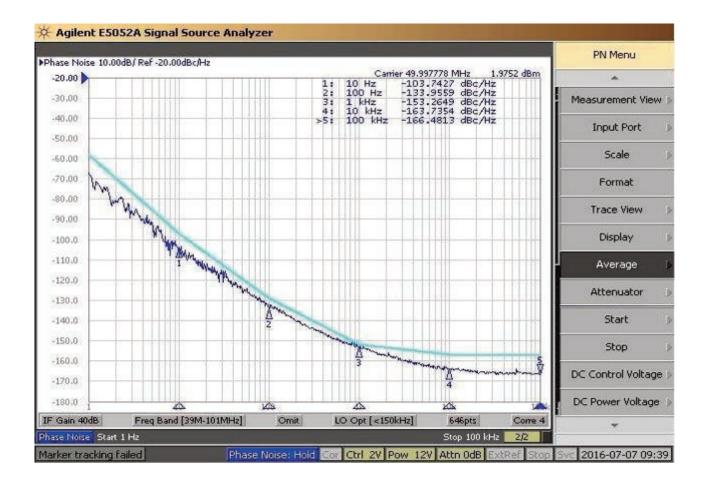
| ELECTRICAL   | SYMBOL                              | TEST CONDITIONS   | LIMITS                              |               |                                      |        |
|--|-------------------------------------|---|-------------------------------------|---------------|--------------------------------------|--------|
| PARAMETERS   | STIMBUL                             | TEST CONDITIONS   | MIN.                                | TYP.          | MAX.                                 | UNIT   |
| Frequency, Nominal   | fo                                  |   | 10                                  |               | 350                                  | MHz    |
| Supply Voltage, Nominal  | Vs                                  |   | 4.75<br>11.4<br>14.25               | 5<br>12<br>15 | 5.25<br>12.6<br>15.75                | V      |
| Input Current, QT8X4   | Is                                  | Nominal Vs  | -                                   | -             | 55                                   | mA     |
| Input Current, QT8X5 or QT8X6  | Is                                  | Nominal Vs  | -                                   | -             | 30                                   | mA     |
| Frequency/Temperature Stability  | Δf/fc (Ta)                          |   | See Tei                             | np. Codes     | s on Pg. 1                           | ppm    |
| Frequency Adjustment Range   | Δf/fo                               |   | ±3                                  | -             | -                                    | ppm    |
| Frequency/Vs, QT8X4  | Δf/fc (Vs)                          | ±5 % Vs @ +25°C   | -                                   | -             | ±1.2                                 | ppm    |
| Frequency/Vs, QT8X5 or QT8X6   | ` ′                                 | ±5 % Vs @ +25°C   | -                                   | -             | ±0.3                                 | ppm    |
| Load   | ,                                   |   | 47.5                                | 50            | 52.5                                 | Ω      |
| Frequency/Load Stability   | Δf/fc (Load)                        | Load ±5%,<br>Vs Nom. @ +25°C  | -                                   | -             | ±0.3                                 | ppm    |
| Aging, Max. (Note 1)   | Δf/fo                               | Over 18 Years   |                                     |               | ±4                                   | ppm    |
| Frequency Stability vs. Vacuum   | Δf/fo                               | Guaranteed by<br>Design, Not Tested   | -                                   | -             | ±0.2                                 | ppm    |
| Short Term Stability   | $\Delta f/dc (\Delta t)$            | $\Delta t = 1s$ (Allan Deviation)   | -                                   | -             | 0.001                                | ppm    |
| Output Level, QT8X4  |                                     |   | 0                                   | -             | -                                    | dBm    |
| Output Level, QT8X5 or QT8X6   |                                     |   | +7                                  | -             | -                                    | dBm    |
| Harmonics  |                                     |   | -                                   | -             | -20                                  | dBc    |
| Sub-Harmonics, Fo > 70MHz  |                                     |   | -                                   | -             | -20                                  | dBc    |
| Spurious   |                                     |   | -                                   | -             | -70                                  | dBc    |
| PHASE NOISE  | SYMBOL                              | TEST CONDITIONS   | (S Option)<br>MAX.                  |               | (L Option)<br>TYP.<br>(NOTE 2)       | UNIT   |
| Phase Noise @ Frequency Offset fo ≤ 75MHz  | $\pounds\left(\Delta f\right)$      | $\Delta f = 10 \text{Hz}$ $\Delta f = 100 \text{Hz}$ $\Delta f = 1 \text{kHz}$ $\Delta f = 10 \text{kHz}$ $\Delta f = 100 \text{kHz}$ | -80<br>-110<br>-135<br>-155<br>-155 | -             | -103<br>-133<br>-153<br>-163<br>-166 | dBc/Hz |
| Phase Noise @ Frequency Offset<br>75MHz < fo ≤ 150MHz<br>Note: Uses 2x Multiplication<br>from lower frequency. | $\mathfrak{L}\left(\Delta f\right)$ | $\Delta f = 10 \text{Hz}$ $\Delta f = 100 \text{Hz}$ $\Delta f = 1 \text{kHz}$ $\Delta f = 10 \text{kHz}$ $\Delta f = 100 \text{kHz}$ | -70<br>-100<br>-125<br>-145<br>-145 | -             | -96<br>-126<br>-146<br>-156<br>-159  | dBc/Hz |
| Phase Noise @ Frequency Offset fo > 150MHz  Note: Uses 3x Multiplication from lower frequency.                 | $\mathfrak{L}\left(\Delta f\right)$ | $\Delta f = 10Hz$ $\Delta f = 100Hz$ $\Delta f = 1kHz$ $\Delta f = 10kHz$ $\Delta f = 100kHz$   | -65<br>-95<br>-120<br>-140<br>-140  | -             | -92<br>-122<br>-142<br>-152<br>-155  | dBc/Hz |

**Note 1:** Consult with factory for better Aging performance.

Note 2: Typical phase noise figures for 5V Supply option shall be 2 - 3 dB higher.



# TYPICAL PHASE NOISE FOR 50MHZ TCXO (SINE WAVE - OPTION L)





# TABLE IV - <u>SCREENING TESTS</u>

| TEST DESCRIPTION                       | STANDARD   | METHOD | CONDITION                   | COMMENTS           |
|--|--|--------|-----------------------------|--------------------|
| Nondestructive Bond Pull               | 883  | 2023   |                             | 2.4-Gram Pull      |
| Internal Visual                        | 883  | 2017   | K                           | Class S            |
| Stabilization Bake                     | 883  | 1008   | B, 48 Hours at +150°C       |                    |
| Thermal Shock                          | 883  | 1011   | A                           |                    |
| Temperature Cycling                    | 883  | 1010   | В                           |                    |
| Constant Acceleration                  | 883  | 2001   | A<br>(5000gs, Y1 Axis Only) |                    |
| Particle Impact Noise Detection (PIND) | PIND) 883 2020   |        | В                           | 5 Passes<br>Note 1 |
| Electrical Test (CMOS)                 | Frequency, VOH,  |        |                             |                    |
| Electrical Test (Sine)                 | Frequency, O   |        |                             |                    |
| Burn-In                                | 883  | 1015   | +125°C for 240 hours        | Note 2             |
| Seal; Fine Leak                        | 883  | 1014   | A1 <u>or</u> B1             |                    |
| Seal; Gross Leak                       | 883  | 1014   | C <u>or</u> B2              |                    |
| Electrical Test (CMOS)                 | Frequency, VOH, VOL, Tr, Tf, DC, Input Current @ +25°C and Temperature Extremes Listed on Electrical Specification |        |                             |                    |
| Electrical Test (Sine)                 | Frequency, Output Levels, Input Current @ +25°C and Temperature Extremes Listed on Electrical Specification        |        |                             |                    |
| Radiographic Inspection                | 883  | 2012   |                             | Class S            |
| External Visual                        | 883  | 2009   |                             |                    |

# **NOTES**

- 1. PIND testing shall be performed using five (5) independent passes and all failures found at the end of each pass are rejected. The survivors of the last pass are acceptable.
- 2. Burn-in shall be under the specified load and nominal voltage conditions.



# TABLE V - GROUP A INSPECTION (NOTE 1)

| TEST DESCRIPTION                  | CONDITION   |  |  |  |
|-----------------------------------|---|--|--|--|
| Frequency-Temperature Stability   |   |  |  |  |
| Input Current                     |   |  |  |  |
| Output Voltage, High (CMOS)       | Vs nominal, Over specified operating temperature extremes.          |  |  |  |
| Output Voltage, Low (CMOS)        | S. F  |  |  |  |
| Output Waveform (CMOS)            |   |  |  |  |
| Duty Cycle (CMOS)                 |   |  |  |  |
| Output Rise And Fall Times (CMOS) |   |  |  |  |
| Output Level (Sine)               | Vs nominal, and $\pm 5\%$ , 25°C and operating temperature extremes |  |  |  |
| Harmonics/Sub-Harmonics (Sine)    |   |  |  |  |
| Phase Noise                       | Vs nominal, 25°C  |  |  |  |
| Frequency Adjustment Range        |   |  |  |  |
| External Visual                   | MIL-STD-883, Method 2009  |  |  |  |

#### **NOTES**

1. Group A inspection shall be performed on units that have passed the screening tests. All electrical performance tests of this specification shall be performed during Group A with the exception of any tests performed as part of the final electrical testing during 100 percent screening.

# TABLE VI - GROUP B INSPECTION

| SUBGROUP | TEST DESCRIPTION                 | CONDITION  |
|----------|----------------------------------|--|
| 1        | Frequency Aging (Note 1)         | MIL-PRF-55310, Para 3.6.34.2   |
| 2        | Hermetic Seal (Note 2)           | Fine Leak - MIL-STD-883, Method 1014, Condition A1 or B1<br>Gross Leak - MIL-STD-883, Method 1014, Condition C or B2 |
| 3        | Electrical (Functional) (Note 2) | Vs nominal, 25°C   |

#### NOTES

- 1. Long term aging projections are performed per MIL-O-55310.
- 2. Shall be performed after completion of frequency aging and before parts are shipped.

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# TABLE VII - GROUP C INSPECTION

(Note 1)

| SUBGROUP | TEST DESCRIPTION  | CONDITION   | QUANTITY<br>(ACCEPT NO.) |  |
|----------|---|---|--------------------------|--|
|          | Vibration (Random)  | MIL-STD-202, Method 214<br>Condition I-K: 46Grms for 3 Minutes in Each Plane.   | (,                       |  |
|          | Shock   | MIL-STD-202, Method 213<br>Condition F: 1500g, 0.5ms Half-Sine Pulse, 3 Blows Each Direction<br>of Three Axes (18 Shocks Total)               |                          |  |
|          | Electrical Test Frequency, Output Levels (Sine), Waveform (CMOS), Input Current @ +25°C |   |                          |  |
|          | Hermetic Seal   | Fine Leak – MIL-STD-883, Method 1014, Condition A1 or B1<br>Gross Leak – MIL-STD-883, Method 1014, Condition C or B2                          |                          |  |
|          | Electrical Test   | Frequency, Output Levels (Sine), Waveform (CMOS), Input Current @ +25°C   |                          |  |
| 1        | Temperature Cycling   | MIL-STD 883, Method 1010, Condition B: 100 Cycles   | 4                        |  |
|          | Electrical Test   | Frequency, Output Levels (Sine), Waveform (CMOS), Input Current @ +25°C   | (0 Failures)             |  |
|          | Ambient Pressure (Non-<br>Operating)  | MIL-PRF-55310 Para. 4.8.46.1  |                          |  |
|          | Electrical Test   | Frequency, Output Levels (Sine), Waveform (CMOS), Input Current @ +25°C   |                          |  |
|          | Storage Temperature   | Low Temperature of -55°C (+0, -5)<br>High Temperature of +150°C (+5,-0)   |                          |  |
|          | Hermetic Seal   | Fine Leak – MIL-STD-883, Method 1014, Condition A1 or B1<br>Gross Leak – MIL-STD-883, Method 1014, Condition C or B2                          |                          |  |
|          | Electrical Test   | Frequency, Output Levels (Sine), Waveform (CMOS), Input Current @ +25°C and Temperature Extremes Listed on Electrical Specification           |                          |  |
|          | Resistance to Soldering<br>Heat   | MIL-STD-202, Method 210, Condition B  |                          |  |
|          | Electrical Test   | Frequency, Output Levels (Sine), Waveform (CMOS), Input Current @ +25°C   |                          |  |
| 3        | Hermetic Seal   | Fine Leak – MIL-STD-883, Method 1014, Condition A1 or B1<br>Gross Leak – MIL-STD-883, Method 1014, Condition C or B2                          | (0 Failures)             |  |
|          | Moisture Resistance   | MIL-STD-202, Method 106   | _                        |  |
|          | Electrical Test   | Frequency, Output Levels (Sine), Waveform (CMOS), Input Current @ $+25^{\circ}$ C and Temperature Extremes Listed on Electrical Specification |                          |  |
|          | Terminal Strength (Lead<br>Integrity)   | MIL-STD-202, Method 211, Condition B  |                          |  |
| 4        | Visual Inspection   | MIL-STD-883, Method 2009  | 1                        |  |
| 4        | Hermetic Seal   | Fine Leak – MIL-STD-883, Method 1014, Condition A1 or B1<br>Gross Leak – MIL-STD-883, Method 1014, Condition C or B2                          | (0 Failures)             |  |
|          | Resistance To Solvents  | MIL-STD 202, Method 215   |                          |  |

# NOTES

1. Samples from Subgroup 1 may be divided and used for subgroups 3 and 4 inspections.

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| DCO     | REV   | REVISION SUMMARY   | PAGE                            | DATE       |  |
|---------|---|--|---------------------------------|------------|--|
|         | 0110, QPDS-0111, QPDS-0112, QPDS-0113, QPDS-0114 TCXO data sheets with updates/additions below. |  | All                             |            |  |
|         |   | phase noise specs as previous data sheets).  |                                 |            |  |
| 6541    | -   | Added Low Noise (Option L) phase noise data.   | 8                               | 3/15/2017  |  |
|         |   | Updated Aging limits and years guaranteed.   | 7, 8                            |            |  |
|         |   | Add document F1221 to Par. 5.3   | 3                               |            |  |
|         |   | Add Par. 6.11 (Breadboard and Engineering Model info)  | 6                               |            |  |
| <b></b> |   | Added note for long term aging for Table VI  | 11                              | 1/25/2017  |  |
| 6731    | A   | Add QCI and DPA verbiage (paragraphs 6.11 and 6.12)  | 6                               | 4/26/2017  |  |
| 6762    | В   | Fix typo where part number 8X1 was 3.3V and 8X2 was 5V. Corrected to 8X1 is 5V and 8X2 is 3.3V (for all 3 packages)  | 2                               | 5/4/2017   |  |
|         |   | Add Note 1 to Table V  | 11                              |            |  |
| 6877    | С   | Add EAR Destination Control Statement  | 1                               | 6/1/2017   |  |
| 7150    | D   | Revise lead length on outline for 24 Pin Flat Pack<br>Was: 2X .500 MIN. Is: 2X .450 MIN.   | 2                               | 8/24/2017  |  |
| 7346    | Е   | Remove 'No Load' from Table III, Input Current conditions  | 8                               | 10/11/2017 |  |
|         |   |  | Para 6.6.3 fix typo: 'tolerant' | 5          |  |
|         |   | Para 6.6.3.1 Fix part numbers to be 8X2 (3.3V) instead of 8X1 (5V)   | 5                               |            |  |
|         |   | Add Screening paragraph 6.11. QCI changed to paragraph 6.12  | 6                               |            |  |
|         |   | Para. 6.12.2 Remove 'The screening test rejects may be used for this test.'  | 6                               |            |  |
| 7537    | F   | Para. 6.12.3 Fix typo (said Group B instead of Group C)  | 6                               | 2/14/2018  |  |
|         |   | Table III: Add Note 2 for L option phase noise on 5V oscillators   | 8                               |            |  |
|         |   | Table VII: Correct Ambient Pressure (non-operating) test conditions (previously used 'operating' test conditions) Change quantity of parts tested in Subgroup 1 to 4 parts (was 5 parts)                     | 12                              |            |  |
| 7864    | G   | Table VII: Remove temperature extreme testing requirement on Electrical Tests between environmental testing (Subgroup 1). Test now only performed at room temperature. End point electricals are unaffected. | 12                              | 4/9/2018   |  |
| 8211    | Н   | Table VII, Subgroup 3: Add Electrical Tests @ 25°C after Resistance to Soldering Heat Add Electrical Tests over temp. after Moisture Resistance testing  | 12                              | 8/8/2018   |  |

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